

Structural Evolution and Microwave Dielectric Properties of $\text{Ba}_{1-x}\text{Sr}_x\text{Ti}_4\text{O}_9$, ($0.0 \leq x \leq 0.06$) Ceramics

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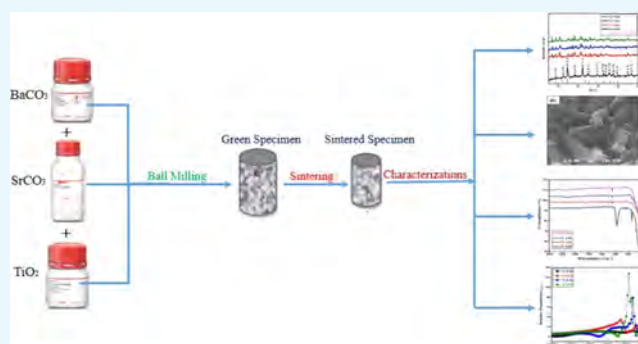
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ABSTRACT: The structural, microstructural, and microwave dielectric properties of $\text{Ba}_{1-x}\text{Sr}_x\text{Ti}_4\text{O}_9$, ($0.0 \leq x \leq 0.06$) ceramics samples synthesized by a conventional route were investigated. These structural, microstructural, and dielectric properties were recorded using X-ray diffraction (XRD), scanning electron microscopy (SEM), and Fourier transform infrared (FTIR) and impedance analyzer spectroscopies. Ti–O octahedral distortion was observed due to Sr^{2+} addition. The microwave dielectric properties were interrelated with various Sr^{2+} concentrations. Excellent microwave dielectric properties, i.e., high relative permittivity ($\epsilon_r = 71.50$) and low dielectric loss ($\tan \delta = 0.0006$), were obtained.



INTRODUCTION

Microwave dielectric devices are used in advanced technological systems such as radar, satellite receiver modules, and mobile telephones.¹ The dielectric material, which is used in telecommunication devices, is termed dielectric resonators (DRs). Dielectric resonators may be used to stabilize microwave oscillators and microwave filter frequencies. Barium titanate (BaTiO_3) and barium tetratitanate (BaTi_4O_9) are candidate materials for DRs in microwave telecommunication and satellite broadcasting.² Microwave DRs provide important advantages in terms of temperature stability, compactness, light weight, and comparatively low costs in the processing of high-dependence frequency devices.³ The physical characteristics required for DRs are as follows.

- High relative permittivity (ϵ_r) to attain reduction of modules in the interpretation of $(1/\epsilon_r^2)$, i.e., size dependence.
- High quality factor ($Q \times f$) values to reduce tangent loss.
- Small temperature coefficient of resonant frequency (τ_f) for stabilization of resonant frequency.

BaTiO_3 , BaTi_4O_9 , and doped BaTi_4O_9 compounds meet these basic requirements for the application of DRs; for example, $\epsilon_r = 39.11$, $Q \times f = 10,700$ GHz, and $\tau_f = +14.2$ ppm/ $^\circ\text{C}$.⁴ However, it is essential for the synthesized dielectric ceramics to have the required microwave dielectric properties. Thus, the processing of single-phase ceramics is necessary to investigate different characterizations. The mixed oxide route involves a high calcination temperature during the reaction of BaCO_3 and TiO_2 (raw materials), and secondary phases may

also be formed during the calcination process.^{5–7} Additionally, the product may be contaminated with impurities from grinding media. Nagas et al. reported the effects of different additives on the phase and microwave dielectric properties of BaTiO_3 and BaTi_4O_9 ceramics.⁸ The dielectric and structural properties of BaTi_4O_9 with different dopants have been studied in the microwave-frequency range.^{9–13} The different types of additives, i.e., Sr in BaTi_4O_9 ceramics, result in multiple phases including BaTi_4O_9 , $\text{Ba}_2\text{Ti}_9\text{O}_{20}$, and TiO_2 .¹¹ Kolar et al.¹⁴ and Negas et al.¹⁵ determined the phases and investigated the microwave dielectric properties with a relatively lower frequency at 1 MHz. Several studies have been executed to improve the microwave dielectric properties of BaTi_4O_9 ceramics by doping different additives, i.e., Sr^{2+} , Ca^{2+} , Pb^{2+} , and Bi^{2+} ions for Ba^{2+} site-ion and Sn^{4+} and Sb^{4+} ions for Ti^{4+} site-ion.^{16,17} Other synthesis routes such as sol gel and co-precipitation may also use to synthesize these products.^{18,19}

Barium tetratitanate (BaTi_4O_9) ceramics is one of the well-known dielectric materials and has been studied by numerous researchers for use in dielectric resonators, thermistors, and electro-optic devices.²⁰ Due to its importance, in the present work, we studied the effect of Sr on phase, surface morphology,

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and the dielectric properties of BaTi₄O₉ ceramics using a controlled mixed oxide solid-state processing route to prepare (Ba_{1-x}Sr_x)Ti₄O₉, 0.0 ≤ *x* ≤ 0.06. These products have been analyzed using X-ray diffraction (XRD), scanning electron microscopy (SEM), and Fourier transform infrared (FTIR) spectroscopy. The dielectric properties of products were measured using impedance spectroscopy.

RESULTS AND DISCUSSION

Phase Analysis. The XRD pattern of (Ba_{1-x}Sr_x)Ti₄O₉, 0.0 ≤ *x* ≤ 0.06 sintered ceramics is shown in Figure 1. The XRD

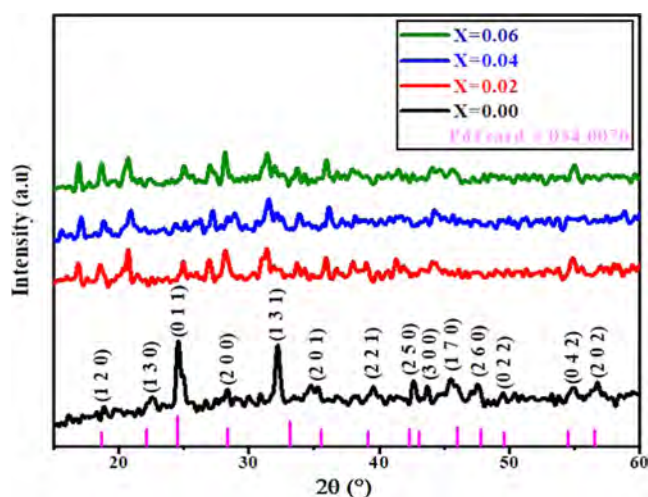


Figure 1. XRD pattern of (Ba_{1-x}Sr_x)Ti₄O₉, 0.0 ≤ *x* ≤ 0.06 ceramics.

studies revealed the formation of the orthorhombic (*Amm*2) structured base composition of barium tetratitanate (BaTi₄O₉), which matches with ICDD/PDF card # 034-0070. It is suggested that Sr²⁺ is incorporated in the lattice of the base composition to partially replace Ba²⁺ ions. A shift of XRD peaks was detected toward higher Bragg-angle (2θ) values with increasing Sr²⁺ content in (Ba_{1-x}Sr_x)Ti₄O₉. The shifting may be due to the substitution of relatively smaller cations of Sr²⁺ (*R*_{Sr} = 1.44 Å) for Ba²⁺ (*R*_{Ba} = 1.61 Å) following the Bragg diffraction law (2*d* Sin θ = *mλ*).^{21,22} A peak at 32.4° emerges with an increase in Sr²⁺, which is attributed to the transformation of the structure from orthorhombic (*Amm*2) at *x* = 0.0 to tetragonal (*I4/m*) at *x* = 0.02, 0.04 and then to cubic (*Pm3m*) at *x* = 0.06. The variation in lattice parameters with increasing Sr²⁺ content is attributed to the phase transition from orthorhombic to tetragonal and then to the cubic structure as listed in Table 1, while Table 2 represents the XRD data of the base composition (BaTi₄O₉).

The particle size and lattice strain of the Ba_{1-x}Sr_xTi₄O₉, (0.00 ≤ *x* ≤ 0.06) sample were determined using the

Table 1. Structural Data of (Ba_{1-x}Sr_x)Ti₄O₉, 0.0 ≤ *x* ≤ 0.06 Ceramics

<i>X</i>	structure	space group	<i>a</i> (Å)	<i>b</i> (Å)	<i>c</i> (Å)
0.00	orthorhombic	<i>Amm</i> 2	6.29400	14.5324	3.79720
0.02	tetragonal	<i>I4/m</i>	10.1434	10.1434	2.96795
0.04	tetragonal	<i>I4/m</i>	10.1434	10.1434	2.96795
0.06	cubic	<i>Pm3m</i>	3.89800	3.89800	3.89800

Table 2. X-ray Diffraction Data for the Base Composition (BaTi₄O₉) at λ = 0.154 nm

2θ _{exp}	2θ _{calc}	<i>I</i> _{exp}	<i>h</i>	<i>k</i>	<i>l</i>	<i>d</i> _{exp}	<i>d</i> _{calc}
18.85	18.63	105.82	1	2	0	4.70211	4.75713
22.45	23.14	140.18	1	3	0	3.95557	3.83916
24.55	24.20	366.33	0	1	1	3.62176	3.67334
28.20	28.34	163.72	2	0	0	3.16072	3.14543
32.30	33.15	303.62	1	3	1	2.76826	2.69921
35.30	36.08	184.69	2	0	1	2.53956	2.48643
38.39	37.61	174.98	2	1	1	2.34196	2.38872
42.55	42.32	195.27	2	5	0	2.12212	2.13312
43.60	43.06	168.88	3	0	0	2.07342	2.09816
45.65	45.99	206.25	1	7	0	1.98496	1.97107
47.75	47.30	179.09	2	6	0	1.90244	1.91949
49.60	49.59	156.41	0	2	2	1.83573	1.83607
54.80	54.51	174.53	0	4	2	1.67319	1.68141
56.85	56.56	199.23	2	0	2	1.61762	1.62522

Williamson–Hall (W–H) technique from the broadening of the XRD peaks.²³

$$\beta \cos \theta = \frac{k\lambda}{D} + 4\epsilon \sin \theta \quad (1)$$

The equation represents a straight line, where ϵ is the gradient (slope) of the line and $k\lambda/D$ is the *y*-intercept.

Consider the standard equation of a straight line,

$$y = mx + c \quad (2)$$

Now, we plot $4 \sin \theta$ on the *x*-axis and $\beta \cos \theta$ on the *y*-axis.

The value of the strain (ϵ_{W-H}) is given by the value of “*m*”, which represents the gradient (slope) of the line, and the crystallite size can be calculated from the *y*-intercept $k\lambda/D$.

Figure 2a–d shows Williamson–Hall (W–H) plots for Ba_{1-x}Sr_xTi₄O₉, (0.00 ≤ *x* ≤ 0.06) ceramics. The W–H is used for deconvoluting shapes (crystalline shapes) and strain that contributes to X-ray line broadening because Scherrer’s formula does not take into account the strain contribution.

Therefore, the average crystallite size, dislocation density, and strain of W–H lie in the 2.9449–11.6128 Å, 0.74152 × 10^{−6}–271.667 × 10^{−6}, and 1.1949 × 10^{−3}–22.871 × 10^{−3} ranges for Ba_{1-x}Sr_xTi₄O₉, (0.00 ≤ *x* ≤ 0.06) ceramics, respectively, as shown in Table 3.

Mathematically, the dislocation density (δ) was calculated using the equation²⁴

$$\delta = \frac{1}{D^2} \quad (3)$$

Dislocation strongly influences many other properties of materials. As the dopant element perfectly replaces the host ions in the crystal lattice, it improves the crystal structure and produces very small crystal defects that can be negligible.

The lattice strain (η) was calculated through the equation^{25,26}

$$\eta = \frac{\beta \cos \theta}{4} \quad (4)$$

In Table 3, the deviation in the calculated lattice strain and crystallite sizes of all prepared Ba_{1-x}Sr_xTi₄O₉, (0.00 ≤ *x* ≤ 0.06) ceramics samples with compositions is shown. When the concentration of the dopant element is increased, the microstrain decreases due to the size of the dopant element being greater than the host ions, as shown in Table 3.

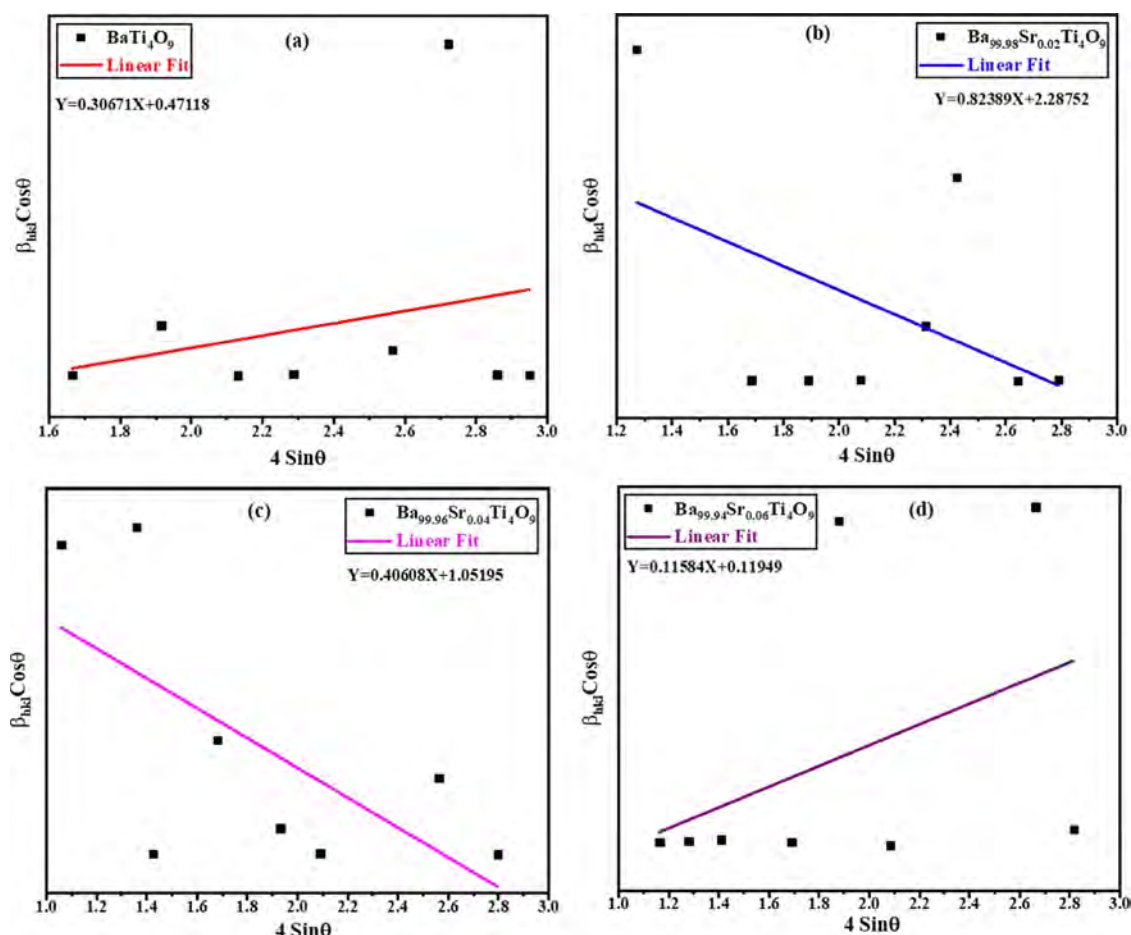


Figure 2. Williamson–Hall plot of $\text{Ba}_{1-x}\text{Sr}_x\text{Ti}_4\text{O}_9$ with Sr content (a) $X = 0.00$, (b) $X = 0.02$, (c) $X = 0.04$, and (d) $X = 0.06$.

Table 3. Williamson–Hall (W–H) Calculated Crystallite Size ($D_{\text{W-H}}$), Dislocation Density ($\delta_{\text{W-H}}$), and Strain ($\eta_{\text{W-H}}$) $\text{Ba}_{1-x}\text{Sr}_x\text{Ti}_4\text{O}_9$, ($0.00 \leq x \leq 0.06$)

composition	$D_{\text{W-H}}$ (nm)	$\delta_{\text{W-H}}$ ($\times 10^{-6} \text{ nm}^{-2}$)	$\eta_{\text{W-H}}$ ($\times 10^{-3}$)
0.00	0.29449	11.5301	4.7118
0.02	0.06067	271.667	22.871
0.04	0.13191	57.4710	10.519
0.06	1.16128	0.74152	1.1949

Microstructural Analysis. The SEM images of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramics sintered at 1300°C in air for 2 h, polished, and thermally etched are shown in Figure 3. The SEM images indicated a dense microstructure with no obvious pores and grains, exhibiting elongated platelike morphologies for the base composition ($x = 0.00$), which is consistent with previous reports for the orthorhombic-structured BaTi_4O_9 .^{27,28} The grain morphologies were observed to change from elongated to rectangular with an increase in the Sr^{2+} content. The grain size for $x = 0.00$ is about $10 \times 1 \mu\text{m}^2$ and decreases with increasing Sr^{2+} content. The variation of relative densities (ρ_r) with increasing Sr^{2+} content is shown in Table 4. The maximum theoretical density achieved is 4.94 g/cm^3 as listed in Table 3. The increase in density may affect the value of the dielectric constant.¹¹

FTIR Spectroscopy. The FTIR spectra of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramics have been studied as shown in Figure 4. Very strong absorption peaks appear near 800 and 1400 cm^{-1} at $x = 0.00$, while minor peaks are also observed at

$x > 0.00$ near 1600 cm^{-1} . These peaks revealed the Ti–O octahedral vibrations according to previous studies on titanates.²⁹ Due to the addition of Sr^{2+} , the concentration in the solid solution of BaTi_4O_9 ceramics is been shifted to higher wavenumbers. Sun et al. reported that only one oxygen vacancy can be used to replace Ba^{2+} ion, while the remaining three oxygen vacancies were used to replace the produced Ti^{4+} ion using respective additives.³⁰ Therefore, Ti–O octahedra are easily distorted or damaged in this way. Some vibrational modes were observed in the FTIR spectrum. Therefore, relative studies of the FTIR spectrum further support the development of redispersibility of polycrystalline BaTi_4O_9 ceramic dielectrics.

Microwave Dielectric Properties. The microwave dielectric properties of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramics have also been investigated, as shown in Figure 5. The dielectric constant (ϵ_r) varies from 21.93 to 71.50, while the variation in dielectric loss ($\tan \delta$) with Sr^{2+} is shown in Table 4. The maximum value of $\tan \delta$ (0.0006) was observed. The frequency-dependent quality factor (Q) is a dimensionless physical quantity, and quantitatively, it is expressed in terms of $Q \times f$.^{31–35}

The variations of $\tan(\delta)$ with frequency (f) for various Sr^{2+} contents in $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ are shown in Figure 6. The orientation polarization decreases with increasing frequency and results in an increase in dielectric loss, which may be attributed to the time lag between flipping dipoles and the applied electric field.^{1,36–38} Microwave

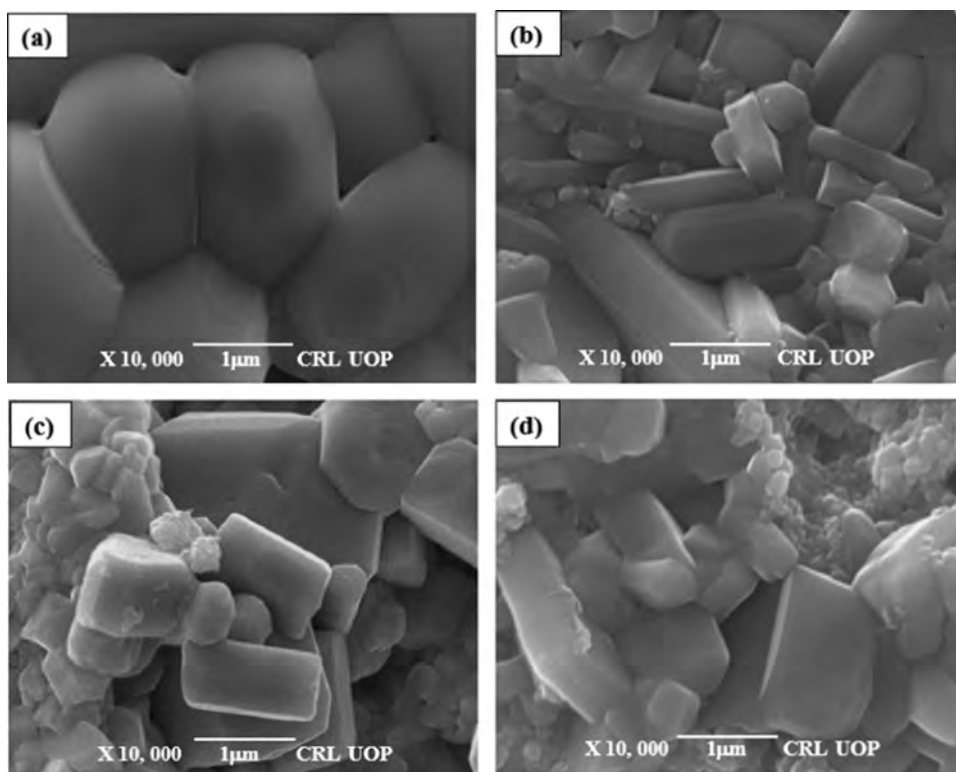


Figure 3. SEM images of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0 \leq x \leq 0.06$ ceramics polished and thermally etched: (a) $x = 0.00$, (b) $x = 0.02$, (c) $x = 0.04$, and (d) $x = 0.06$ indicating a decrease in grain size and change in grain morphologies with an increase in Sr^{2+} content.

Table 4. Density Parameters and Dielectric Properties of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ Ceramics^a

x	ρ_a (g/cm ³)	ρ_t (g/cm ³)	ρ_r (%)	$\tan \delta$	ϵ_r
0.00	4.26	4.402	96.77	0.0008	21.93
0.02	4.40	4.840	90.90	0.0006	47.84
0.04	4.40	4.940	89.07	0.0043	71.50
0.06	4.07	4.540	89.64	0.0044	52.50

^aNote: ρ_a = apparent density, ρ_t = theoretical density, and ρ_r = relative density.

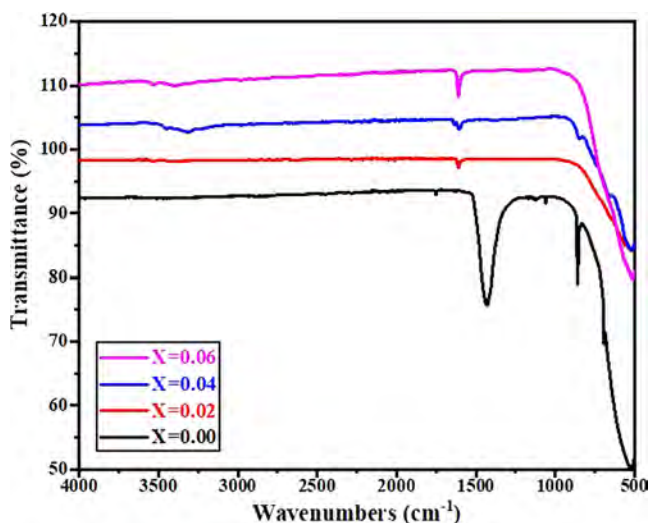


Figure 4. FTIR spectra of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramics.

dielectric material is usually characterized by high relative permittivity and a low tangent loss. The theoretical justification

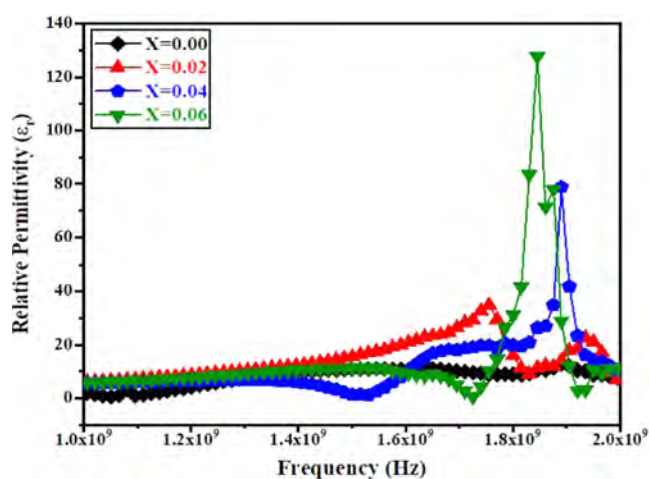


Figure 5. Variation of ϵ_r with the frequency of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramic.

is very important for this case in which ionic crystals with an optical mode of vibrations resonate at a frequency of (10^{13} Hz) . In the frequency range from approximately 10^9 to 10^{11} Hz , the dielectric dispersion theory shows the contribution to polarization from the ionic displacement to be nearly constant and the loss to increase with frequency.³⁹

CONCLUSIONS

The structural, microstructural, and microwave dielectric properties of $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ sintered ceramics were investigated via a solid-state route. It is found that the dielectric constant (ϵ_r) and dielectric loss ($\tan \delta$) values improved with Sr^{2+} content. The $(\text{Ba}_{0.98}\text{Sr}_{0.02})\text{Ti}_4\text{O}_9$

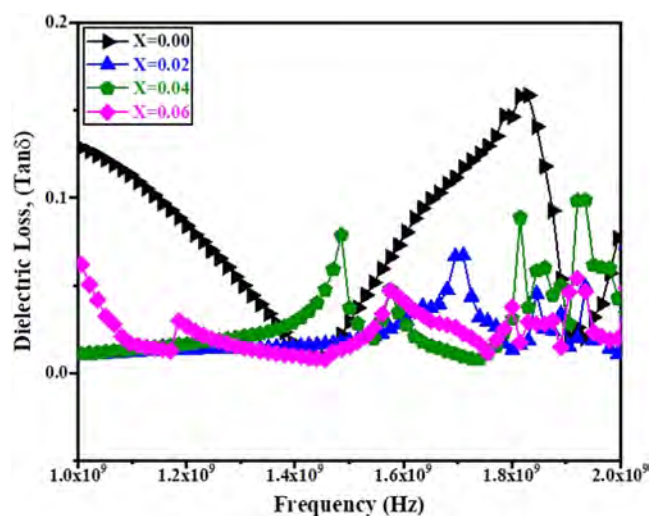


Figure 6. Variation of $\tan \delta$ with frequency (f) for various Sr^{2+} contents in $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramics.

ceramics was found to have the best ϵ_r and $\tan \delta$ values. The microwave dielectric properties of $(\text{Ba}_{0.98}\text{Sr}_{0.02})\text{Ti}_4\text{O}_9$ ceramics intensely depend upon density. Outstanding microwave dielectric properties of $\epsilon_r \sim 47.84$ and $\tan \delta \sim 0.0006$ were obtained for $(\text{Ba}_{0.98}\text{Sr}_{0.02})\text{Ti}_4\text{O}_9$ ceramics sintered at 1300°C for 2 h. We obtained excellent microwave dielectric properties in this study for the application of microwave wireless communication systems.

EXPERIMENTAL PROCEDURE

BaCO_3 (purity 99.0%, Chemdad, China), SrCO_3 (purity 99.5%, ABCO, U.K.), and TiO_2 (purity 99.9%, Sigma) were chosen as raw starting materials to prepare $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramics material for microwave dielectric devices. The raw materials, i.e., BaCO_3 , SrCO_3 , and TiO_2 , were thoroughly mixed according to the $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0 \leq x \leq 0.06$ stoichiometric ratios, where the mole ratio of A site-ion and B site-ion was 1:4. Distilled water was added to the weighed raw material powder in a polyethylene jar container along with 5 mm diameter zirconia balls and then milled by horizontal ball milling for 24 h. The mixture powders were dried at 100°C for 24 h in an air atmosphere, and after drying, the reactant mixture was loaded in an alumina crucible and calcined at 1000°C for 3 h in air at $10^\circ\text{C}/\text{min}$ in a heating/cooling rate. After calcination, the product powder was ground and then pressed into green body discs (5 mm thickness and 10 mm diameter) under a pressure of 80 MPa using a manual pellet press (CARVER). The pellet samples were sintered at 1300°C for 2 h in air with a heating/cooling rate of $10^\circ\text{C}/\text{min}$. The crystalline phases of the calcined $(\text{Ba}_{1-x}\text{Sr}_x)\text{Ti}_4\text{O}_9$, $0.0 \leq x \leq 0.06$ ceramics samples were identified using X-ray diffraction (XRD) (JDX-3532, JEOL, Japan) with a $\text{Cu K}\alpha$ ($\lambda = 0.15406$ nm) radiation source operated at 40 mA and 40 kV in a wide range of Bragg's angle 2θ ($20^\circ < 2\theta < 80^\circ$) at a scanning rate of $2^\circ/\text{min}$. The surface morphology information was obtained using SEM (JSM-5910, JEOL Japan), while the microwave dielectric properties of the sintered samples were measured at microwave frequencies using impedance spectroscopy (Agilent 4287A).

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Author Contributions

This work was carried out in collaboration with all authors. A.A. prepared samples and wrote the original draft of the manuscript. A.Z. performed the final writing review, corrections, and editing. M.A. helped in methodology and measurements. S.A.A. and M.M. prepared content analysis and graphical arrangements. K.B. helped with software and validation. K.A. and M.A. helped with formal analysis and provided funding acquisition. All authors have read and approved the final manuscript.

Notes

The authors declare no competing financial interest.

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REFERENCES

- (1) Sebastian, M. T. *Dielectric Materials for Wireless Communication*; Elsevier: Oxford, UK, 2010.
- (2) Cava, R. J. Dielectric materials for applications in microwave communications. *J. Mater. Chem.* **2001**, *11*, 54–62.
- (3) Freer, R.; Azough, F. Microstructural engineering of microwave dielectric ceramics. *J. Eur. Ceram. Soc.* **2008**, *28*, 1433–1441.
- (4) Rase, D. E.; Roy, R. Phase equilibria in the system $\text{BaO}-\text{TiO}_2$. *J. Am. Ceram. Soc.* **1955**, *38*, 102–113.
- (5) Ali, A.; Uddin, S.; Iqbal, Z.; Lal, M.; Zaman, A. Structural, optical and microwave dielectric properties of barium tetra titanate (BaTi_4O_9) ceramics. *J. Optoelectron. Adv. Mater.* **2021**, *23*, 48–52.

- (6) Phule, P. P.; Risbud, S. H. Low-temperature synthesis and processing of electronic materials in the BaO–TiO₂ system. *J. Mater. Sci.* **1990**, *25*, 1169–1183.
- (7) Negas, T.; Yeager, G.; Bell, S.; Coats, N.; Minis, I. BaTi₄O₉/Ba₂Ti₉O₂₀-based ceramics resurrected for modern microwave applications. *Am. Ceram. Soc. Bull.* **1993**, *72*, 80–89.
- (8) Mhaisalkar, S. G.; Readey, D. W.; Akbar, S. A.; Dutta, P. K.; Sumner, M. J.; Rokhlin, R. Infrared reflectance spectra of doped BaTi₄O₉. *J. Solid State Chem.* **1991**, *95*, 275–282.
- (9) Nishigaki, S.; Yano, S.; Kato, H.; Hirai, T.; Nonomura, T. BaO–TiO₂–WO₃ Microwave Ceramics and Crystalline BaWO₄. *J. Am. Ceram. Soc.* **1988**, *71*, C–11.
- (10) Ern, V.; Newnham, R. E. Effect of WO₃ on dielectric properties of BaTiO₃ ceramics. *J. Am. Ceram. Soc.* **1961**, *44*, 199.
- (11) Mhaisalkar, S. G.; Lee, W. E.; Readey, D. W. Processing and characterization of BaTi₄O₉. *J. Am. Ceram. Soc.* **1989**, *72*, 2154–2158.
- (12) Kolar, D.; Gaberscek, S.; Volavsek, B.; Parker, H. S.; Roth, R. S. Synthesis and crystal chemistry of BaNd₂Ti₃O₁₀, BaNd₂Ti₅O₁₄, and Nd₄Ti₉O₂₄. *J. Solid State Chem.* **1981**, *38*, 158–164.
- (13) Davies, P. K.; Roth, R. S.; Clevinger, M. A. editors. *Chemistry of Electronic Ceramic Materials*; CRC Press, 1991.
- (14) Pei, J.; Yue, Z.; Zhao, F.; Gui, Z.; Li, L. Effects of Silver Doping on the Sol–Gel-Derived Ba₄(Nd_{0.75}Sm_{0.3})_{9.33}Ti₁₈O₅₄ Microwave Dielectric Ceramics. *J. Am. Ceram. Soc.* **2007**, *90*, 3131–3137.
- (15) Qin, N.; Liu, X. Q.; Chen, X. M. Thermal Expansion and High-Temperature Phase Transition of Ba_{6–3x}Ln_{8+2x}Ti₁₈O₅₄ (Ln = La, Nd, and Sm) Ceramics. *J. Am. Ceram. Soc.* **2007**, *90*, 2912–2917.
- (16) Okawa, T.; Imaeda, M.; Ohsato, H. Microwave dielectric properties of Bi-added Ba₄Nd_{9+1/3}Ti₁₈O₅₄ solid solutions. *Jpn. J. Appl. Phys.* **2000**, *39*, 5645–5649.
- (17) Wu, Y. J.; Chen, X. M. Bismuth/samarium cosubstituted Ba_{6–3x}Nd_{8+2x}Ti₁₈O₅₄ microwave dielectric ceramics. *J. Am. Ceram. Soc.* **2000**, *83*, 1837–1839.
- (18) Belous, A. G.; Ovchar, O. V.; Valant, M.; Suvorov, D.; Kolar, D. The effect of partial isovalent substitution in the A-sublattice on MW properties of materials based on Ba_{6–x}Ln_{8+2x/3}Ti₁₈O₅₄ solid solutions. *J. Eur. Ceram. Soc.* **2001**, *21*, 2723–2730.
- (19) Avinash, M.; Muralidharan, M.; Selvakumar, S.; Hussain, S.; Sivaji, K. Induced ferromagnetism and enhanced optical behaviour in indium-doped barium stannate system. *J. Mater. Sci.: Mater. Electron* **2020**, *31*, 3375–3386.
- (20) Chen, X. M.; Li, Y. A- and B Site Cosubstituted Ba_{6–3x}Sm_{8+2x}Ti₁₈O₅₄ Microwave Dielectric Ceramics. *J. Am. Ceram. Soc.* **2002**, *85*, 579–584.
- (21) Tong, X. D.; Sun, Y. Nd–Fe–B alloy-densified agarose gel for expanded bed adsorption of proteins. *J. Chromatogr. A* **2002**, *943*, 63–75.
- (22) Wah Chan, L.; Liu, X.; Heng, P. W. Liquid phase coating to produce controlled-release alginate microspheres. *J. Microencapsulation* **2005**, *22*, 891–900.
- (23) Avinash, M.; Muralidharan, M.; Sivaji, K. Structural, optical and magnetic behaviour of Cr doped BaSnO₃ perovskite nanostructures. *Phys. B* **2019**, *570*, 157–65.
- (24) Zaman, A.; Uddin, S.; Mehboob, N.; Ali, A. Structural investigation and improvement of microwave dielectric properties in Ca(Hf_{1-x}Ti_x)O₃ ceramics. *Phys. Scr.* **2020**, *96*, No. 025701.
- (25) Zaman, A.; Uddin, S.; Mehboob, N.; Ali, A.; Ahmad, A.; Bashir, K. Effect of Zr⁴⁺ on the structural and microwave dielectric properties of CaTiO₃ ceramics. *Ferroelectrics* **2021**, *577*, 143–152.
- (26) Abbas, M.; Ullah, R.; Ullah, K.; Sultana, F.; Mahmood, A.; Mateen, A.; Zhang, Y.; Ali, A.; Althubeiti, K.; Mushtaq, M.; Zaman, A. Structural, optical, electrical and dielectric properties of (Sr_{1-x}Mg_x)(Sn_{0.5}Ti_{0.5})O₃ (X = 0.00, 0.25, 0.50, 0.75) ceramics via solid state route. *Ceram. Int.* **2021**, *47*, 30129–30136.
- (27) Wang, S. F.; Hsu, Y. F.; Wang, Y. R.; Cheng, L. T.; Hsu, Y. C.; Chu, J. P.; Huang, C. Y. Densification, microstructural evolution and dielectric properties of Ba_{6–3x}(Sm_{1–y}Nd_y)_{8+2x}Ti₁₈O₅₄ microwave ceramics. *J. Am. Ceram. Soc.* **2006**, *26*, 1629–1635.
- (28) Qin, N.; Liu, X. Q.; Chen, X. M. Phase Transition in Ba_{6–3x}(Sm_{1–y}La_y)_{6+2x}Ti₁₈O₅₄ (x = 0.5) Ceramics. *J. Am. Ceram. Soc.* **2006**, *89*, 2796–2803.
- (29) Perry, C. H.; Khanna, B. N.; Rupprecht, G. Infrared studies of perovskite titanates. *Phys. Rev.* **1964**, *135*, No. A408.
- (30) Sun, D.; Jin, X.; Liu, H.; Zhu, J.; Zhu, Y.; Zhu, Y. Investigation on FTIR spectrum of barium titanate ceramics doped with alkali ions. *Ferroelectrics* **2007**, *355*, 145–148.
- (31) Wu, J. M.; Chang, M. C.; Yao, P. C. Reaction Sequence and Effects of Calcination and Sintering on Microwave Properties of (Ba, Sr)O–Sm₂O₃–TiO₂ Ceramics. *J. Am. Ceram. Soc.* **1990**, *73*, 1599–1605.
- (32) Wang, S. F.; Yang, T. C.; Chiang, C. C.; Tsai, S. H. Effects of additives on the phase formation and microstructural evolution of Ba₂Ti₉O₂₀ microwave ceramic. *Ceram. Int.* **2003**, *29*, 77–81.
- (33) Wu, J. M.; Wang, H. W. Factors affecting the formation of Ba₂Ti₉O₂₀. *J. Am. Ceram. Soc.* **1988**, *71*, 869–875.
- (34) Purohit, R. D.; Tyagi, A. K. Synthesis of monophasic Ba₂Ti₉O₂₀ through gel combustion. *J. Mater. Chem.* **2002**, *12*, 1218–1221.
- (35) Shannon, R. D. Revised effective ionic radii and systematic studies of interatomic distances in halides and chalcogenides. *Acta Crystallogr., Sect. A: Cryst. Phys., Diff., Theor. Gen. Crystallogr.* **1976**, *32*, 751–767.
- (36) Zaman, A.; Uddin, S.; Mehboob, N. Synthesis and Microwave Dielectric Characterization of Ca_{1-x}Sr_xTiO₃, Low-Loss Ceramics. *Iran J. Sci. Technol., Trans. A: Sci.* **2021**, *45*, 367–371.
- (37) Ma, H.; Zhang, W.; Kong, X.; Uemura, S.; Kusunose, T.; Feng, Q. BaTi₄O₉ mesocrystal: Topochemical synthesis, fabrication of ceramics, and relaxor ferroelectric behavior. *J. Alloys Compd.* **2019**, *777*, 335–343.
- (38) Luo, T.; He, L.; Yang, H.; Yu, H. Phase evolution and microwave dielectric properties of BaTi₄O₉ ceramics prepared by reaction sintering method. *Int. J. Appl. Ceram. Technol.* **2019**, *16*, 146–151.
- (39) Sebastian, M. T.; Ubbi, R.; Jantunen, H. Low-loss dielectric ceramic materials and their properties. *Int. Mater. Rev.* **2015**, *60*, 392–412.